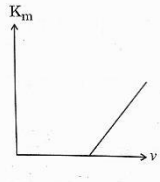
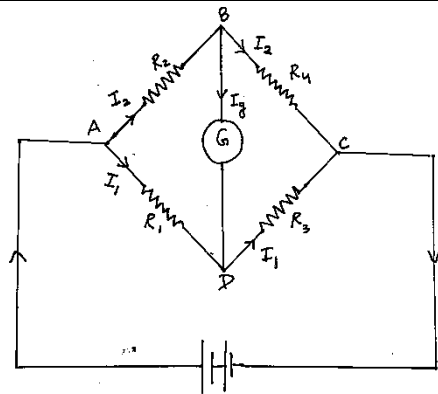


MARKING SCHEME : PHYSICS (042)

CODE :55/3/1

Q.NO.	VALUE POINTS/ EXPECTED ANSWERS	MARKS	TOTAL MARKS								
SECTION-A											
1.	(B) Spherical surface	1	1								
2.	(B) 1.6×10^{-18} J	1	1								
3.	(C) $-(0.24 \text{ nT}) \hat{k}$	1	1								
4.	(D) remain stationary	1	1								
5.	(B) 0.3 MB	1	1								
6.	(C) 15.0 V	1	1								
7.	(B) I is decreased and A is increased	1	1								
8.	(B) Gamma rays	1	1								
9.	(B) 2	1	1								
10.	(C) 	1	1								
11.	(B) decreased by 87.5%	1	1								
12.	(B) 0.05 eV	1	1								
13.	(D) Assertion (A) is false and Reason (R) is also false.	1	1								
14.	(C) Assertion (A) is true but Reason (R) is false.	1	1								
15.	(A) Both Assertion (A) and Reason (R) are true and Reason (R) is the correct explanation of the Assertion(A).	1	1								
16.	(A) Both Assertion (A) and Reason (R) are true and Reason (R) is the correct explanation of the Assertion(A).	1	1								
SECTION- B											
17.	<p>(a) <table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="padding: 5px;">Meaning of relaxation time</td> <td align="right" style="padding: 5px;">$\frac{1}{2}$</td> </tr> <tr> <td style="padding: 5px;">Derivation of R</td> <td align="right" style="padding: 5px;">$1 \frac{1}{2}$</td> </tr> </table></p> <p>Average time between two successive collisions of electron in presence of electric field</p> <p>Drift velocity of an electron</p> $v_d = \frac{eE}{m} \tau \quad \text{--- (i)}$ <p>Current flowing through a conductor of length l and area of cross section A</p> $I = neAv_d \quad \text{--- (ii)}$ $I = \frac{ne^2 AE \tau}{m} = \frac{ne^2 A \tau V}{ml}$ $R = \frac{V}{I} = \frac{ml}{ne^2 \tau A}$ <p align="center">OR</p> <p>(b) <table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="padding: 5px;">Circuit diagram of Wheatstone bridge</td> <td align="right" style="padding: 5px;">$\frac{1}{2}$</td> </tr> <tr> <td style="padding: 5px;">Obtaining the condition when no current flows through galvanometer</td> <td align="right" style="padding: 5px;">$1 \frac{1}{2}$</td> </tr> </table></p>	Meaning of relaxation time	$\frac{1}{2}$	Derivation of R	$1 \frac{1}{2}$	Circuit diagram of Wheatstone bridge	$\frac{1}{2}$	Obtaining the condition when no current flows through galvanometer	$1 \frac{1}{2}$	<p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p>	<p>2</p>
Meaning of relaxation time	$\frac{1}{2}$										
Derivation of R	$1 \frac{1}{2}$										
Circuit diagram of Wheatstone bridge	$\frac{1}{2}$										
Obtaining the condition when no current flows through galvanometer	$1 \frac{1}{2}$										



By applying Kirchoff's loop rule to closed loops ADBA and CBDC

$$-I_1R_1 + 0 + I_2R_2 = 0 \quad \text{-----(i) } [I_g=0]$$

$$I_2R_4 + 0 - I_1R_3 = 0 \quad \text{-----(ii)}$$

From eq (i)-

$$\frac{I_1}{I_2} = \frac{R_2}{R_1}$$

From eq (ii)-

$$\frac{I_1}{I_2} = \frac{R_4}{R_3}$$

Hence,

$$\frac{R_2}{R_1} = \frac{R_4}{R_3}$$

1/2

1/2

1/2

1/2

2

18.

Finding the focal length of objective lens

2

Magnifying power = 24 , Distance between lenses =150 cm

$$\frac{f_o}{f_e} = 24$$

$$f_o + f_e = 150 \text{ cm}$$

$$f_e = 6 \text{ cm}$$

$$f_o = 144 \text{ cm}$$

1/2

1/2

1/2

1/2

2

19.

(a) Explanation of magnification

1

(b) Explanation

1

(a) Yes, it offers magnification.

We can keep the small object much closer to the eye than 25 cm and hence have it subtend a large angle.

(b) Yes,

Rays converging to a point behind a plane or convex mirror are reflected to a point in front of the mirror on a screen

1/2

1/2

1/2

1/2

2

20.

Calculation of number of photons per second

2

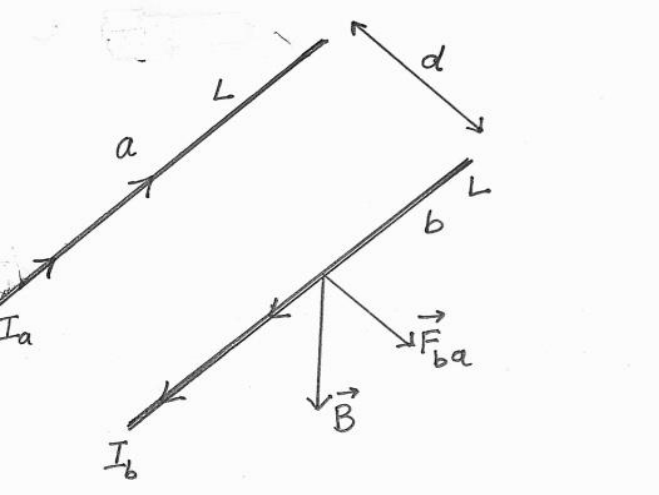
Total Energy gained per second from photon= IA

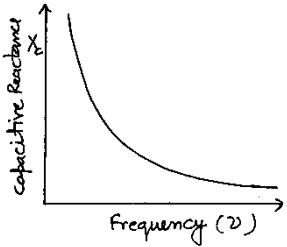
$$E = N h \nu$$

1/2



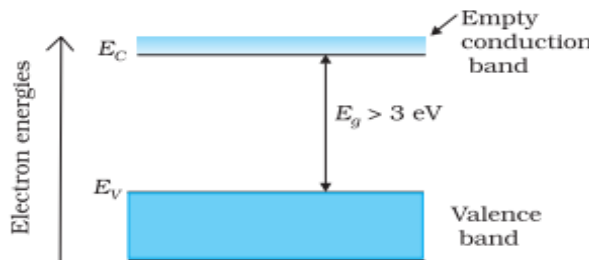
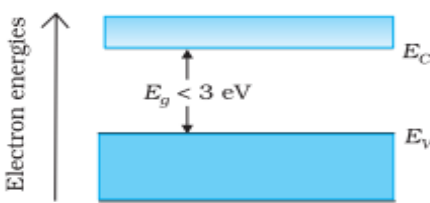
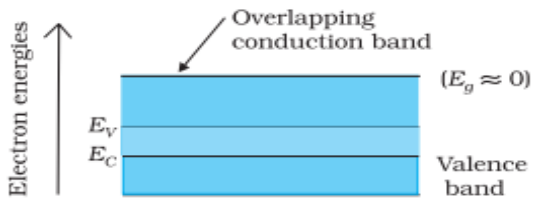
	$IA = N \times \frac{hc}{\lambda}$ $N = \frac{[IA]\lambda}{hc}$ $N = \frac{[0.1 \times 10^{-9} \times 0.4 \times 10^{-4}] \times 500 \times 10^{-9}}{6.6 \times 10^{-34} \times 3 \times 10^8}$ $N = 1.01 \times 10^4$	1	2
21.	<div style="border: 1px solid black; padding: 5px; margin-bottom: 10px;"> Calculation of concentration of holes & electrons 2 </div> $n_e n_h = n_i^2$ $n_h \approx 5 \times 10^{22} / m^3$ $n_e = \frac{n_i^2}{n_h}$ $n_e = \frac{(1.5 \times 10^{16})^2}{5 \times 10^{22}}$ $n_e = 4.5 \times 10^9 / m^3$ <p style="text-align: center;">$n_h > n_e$, it is a p-type crystal</p>	1/2 1/2 1/2	2
SECTION- C			
22.	<div style="border: 1px solid black; padding: 5px; margin-bottom: 10px;"> Determination of current in branches AB, AC, BC 1+1+1 </div> <p>For closed loop ADCA ,</p> $10 - 4(I_1 - I_2) + 2(I_2 + I_3 - I_1) - I_1 = 0$ $7I_1 - 6I_2 - 2I_3 = 10 \text{ -----(i)}$ <p>For closed loop ABCA ,</p> $10 - 4I_2 - 2(I_2 + I_3) - I_1 = 0$ $I_1 + 6I_2 + 2I_3 = 10 \text{ -----(ii)}$ <p>For closed loop BCDED ,</p> $5 - 2(I_2 + I_3) - 2(I_2 + I_3 - I_1) = 0$ $2I_1 - 4I_2 - 4I_3 = -5 \text{ -----(iii)}$ <p>Current in branch AB = $I_2 = \frac{5}{8} A$</p> <p>Current in branch AC = $I_1 = 2.5A$</p> <p>Current in branch BC = $I_2 + I_3 = 2.5A$</p>	1/2 1/2 1/2	3

<p>23.</p>	<table border="1" style="width: 100%;"> <tr> <td>Reason for exerting force on straight parallel conductors</td> <td style="text-align: right;">1/2</td> </tr> <tr> <td>Derivation for force per unit length</td> <td style="text-align: right;">2</td> </tr> <tr> <td>Explanation of nature of Force</td> <td style="text-align: right;">1/2</td> </tr> </table> <p>One conductor experiences a force due to magnetic field of the other conductor</p>  <p>Magnetic field produced by conductor 'a' at all points along the length of conductor 'b'</p> $B_a = \frac{\mu_0 I_a}{2\pi d}$ <p>Force on conductor 'b' due to this magnetic field</p> $F_{ba} = I_b L B_a$ $F_{ba} = \frac{\mu_0 I_a I_b L}{2\pi d}$ $f_{ba} = \frac{F_{ba}}{L} = \frac{\mu_0 I_a I_b}{2\pi d} \quad \text{directed away from a}$ $f_{ab} = \frac{F_{ab}}{L} = \frac{\mu_0 I_a I_b}{2\pi d} \quad \text{directed away from b}$ <p>Repulsive, the forces acting on them are away from each other.</p>	Reason for exerting force on straight parallel conductors	1/2	Derivation for force per unit length	2	Explanation of nature of Force	1/2	<p style="text-align: center;">1/2</p> <p style="text-align: center;">1/2</p> <p style="text-align: center;">1/2</p> <p style="text-align: center;">1/2</p> <p style="text-align: center;">1/2</p>	<p style="text-align: center;">3</p>						
Reason for exerting force on straight parallel conductors	1/2														
Derivation for force per unit length	2														
Explanation of nature of Force	1/2														
<p>24.</p>	<table border="1" style="width: 100%;"> <tr> <td>(a) Identifying the element X</td> <td style="text-align: right;">1/2</td> </tr> <tr> <td>(b) Writing the formula for reactance</td> <td style="text-align: right;">1/2</td> </tr> <tr> <td>(c) Showing variation of reactance with frequency</td> <td style="text-align: right;">1</td> </tr> <tr> <td>(d) Explanation of behavior of element with</td> <td></td> </tr> <tr> <td> (i) an ac circuit</td> <td style="text-align: right;">1/2</td> </tr> <tr> <td> (ii) a dc circuit</td> <td style="text-align: right;">1/2</td> </tr> </table> <p>(a) Capacitor</p> <p>(b) $X_c = \frac{1}{\omega C}$</p>	(a) Identifying the element X	1/2	(b) Writing the formula for reactance	1/2	(c) Showing variation of reactance with frequency	1	(d) Explanation of behavior of element with		(i) an ac circuit	1/2	(ii) a dc circuit	1/2	<p style="text-align: center;">1/2</p> <p style="text-align: center;">1/2</p>	
(a) Identifying the element X	1/2														
(b) Writing the formula for reactance	1/2														
(c) Showing variation of reactance with frequency	1														
(d) Explanation of behavior of element with															
(i) an ac circuit	1/2														
(ii) a dc circuit	1/2														

	<p>(c)</p>  <p>(d) (i) For ac X_c is finite and therefore allows the ac to pass. (ii) For dc X_c is infinite and therefore does not allow the dc to pass.</p>	<p>1</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p>	<p>3</p>						
25.	<table border="1" style="width: 100%;"> <tbody> <tr> <td>(a) Finding the wavelength and frequency</td> <td>1+1</td> </tr> <tr> <td>(b) Finding the amplitude of magnetic field</td> <td>$\frac{1}{2}$</td> </tr> <tr> <td>(c) Writing expression for magnetic field</td> <td>$\frac{1}{2}$</td> </tr> </tbody> </table> <p>(a) $k = \frac{2\pi}{\lambda}$ $\lambda = \frac{2\pi}{K} = \frac{4\pi}{3} \text{ m} = 4.18 \text{ m}$ $\omega = 2\pi\nu$ $\nu = \frac{\omega}{2\pi} = \frac{4.5 \times 10^8}{2\pi} \text{ Hz}$ $\nu = \frac{9}{4\pi} \times 10^8 \text{ Hz}$ $\nu = 7.16 \times 10^{-1} \text{ Hz}$</p> <p>(b) $B_0 = \frac{E_0}{c}$ $B_0 = \frac{6.3}{3 \times 10^8} = 2.1 \times 10^{-8} \text{ T}$</p> <p>(c) $\vec{B} = 2.1 \times 10^{-8} [(\cos 1.5 \text{ rad/m}) y + (4.5 \times 10^8 \text{ rad/s}) t] \hat{k} \text{ T}$</p>	(a) Finding the wavelength and frequency	1+1	(b) Finding the amplitude of magnetic field	$\frac{1}{2}$	(c) Writing expression for magnetic field	$\frac{1}{2}$	<p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p>	<p>3</p>
(a) Finding the wavelength and frequency	1+1								
(b) Finding the amplitude of magnetic field	$\frac{1}{2}$								
(c) Writing expression for magnetic field	$\frac{1}{2}$								
26.	<table border="1" style="width: 100%;"> <tbody> <tr> <td>Statements of Bohr's first and second Postulates</td> <td>$\frac{1}{2} + \frac{1}{2}$</td> </tr> <tr> <td>Derivation of expression for radius of n^{th} orbit</td> <td>2</td> </tr> </tbody> </table> <ul style="list-style-type: none"> Bohr's first postulate An electron in an atom revolves in certain stable orbits without the emission of radiant energy. Bohr's second postulate Electron revolves around the nucleus only in those orbits for which the angular momentum is integral multiple of $\frac{h}{2\pi}$. <p>Electrostatic force between revolving electron and nucleus provides requisite centripetal force</p> $\frac{mv_n^2}{r_n} = \frac{1}{4\pi\epsilon_0} \frac{e^2}{r_n^2}$	Statements of Bohr's first and second Postulates	$\frac{1}{2} + \frac{1}{2}$	Derivation of expression for radius of n^{th} orbit	2	<p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p> <p>$\frac{1}{2}$</p>			
Statements of Bohr's first and second Postulates	$\frac{1}{2} + \frac{1}{2}$								
Derivation of expression for radius of n^{th} orbit	2								



	$v_n = \frac{e}{\sqrt{4\pi\epsilon_0 m r_n}} \quad \text{-----(i)}$ $m v_n r_n = \frac{nh}{2\pi} \quad \text{-----(ii)}$ <p>using equations (i) and (ii)</p> $r_n = \left(\frac{n^2}{m}\right) \left(\frac{h}{2\pi}\right)^2 \frac{4\pi\epsilon_0}{e^2}$	$\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$	3								
27.	<table border="1" style="width: 100%;"> <tbody> <tr> <td>(a) Definition of atomic mass unit (u)</td> <td style="text-align: right;">1</td> </tr> <tr> <td>(b) Calculation of energy required</td> <td style="text-align: right;">2</td> </tr> </tbody> </table> <p>(a) atomic mass unit (u) is defined as 1/12th of the mass of the carbon (¹²C) atom.</p> <p>(b) $m({}_1H^2) \rightarrow m({}_1H^1) + m({}_0n^1)$</p> $Q = (m_R - m_P) \times 931.5 \text{ MeV}$ $= (2.014102 - 1.007825 - 1.008665) \times 931.5 \text{ MeV}$ $= -0.002388 \times 931.5 \text{ MeV}$ $= -2.224 \text{ MeV}$ <p>Hence energy required is 2.224 MeV</p>	(a) Definition of atomic mass unit (u)	1	(b) Calculation of energy required	2	1 $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$ $\frac{1}{2}$	3				
(a) Definition of atomic mass unit (u)	1										
(b) Calculation of energy required	2										
28.	<p>(a)</p> <table border="1" style="width: 100%;"> <tbody> <tr> <td>(a) Drawing the circuit diagram for V-I characteristics</td> <td style="text-align: right;">1</td> </tr> <tr> <td>Salient features of V-I characteristics in</td> <td></td> </tr> <tr> <td> (i) Forward biasing</td> <td style="text-align: right;">1</td> </tr> <tr> <td> (ii) Reverse biasing</td> <td style="text-align: right;">1</td> </tr> </tbody> </table> <div style="text-align: center;"> <p>(a) (b)</p> </div> <p style="text-align: center;">[any one circuit diagram]</p> <p>Salient features</p> <p>(i) Forward biasing- After threshold voltage or cut in voltage diode current increases significantly (exponentially), even for a small increase in the diode bias voltage.</p> <p>(ii) Reverse biasing- Current is very small (~μA) and almost remains constant and it increases rapidly after breakdown voltage.</p> <p style="text-align: center;">OR</p>	(a) Drawing the circuit diagram for V-I characteristics	1	Salient features of V-I characteristics in		(i) Forward biasing	1	(ii) Reverse biasing	1	1 1 1	
(a) Drawing the circuit diagram for V-I characteristics	1										
Salient features of V-I characteristics in											
(i) Forward biasing	1										
(ii) Reverse biasing	1										

	<p>(b) Energy band diagrams Difference between (i) an insulator (ii) a semiconductor (iii) a metal 1+1+1</p> <p>(i) </p> <p>(ii) </p> <p>(iii) </p>	<p style="text-align: center;">1</p> <p style="text-align: center;">1</p> <p style="text-align: center;">1</p>	<p style="text-align: center;">3</p>								
SECTION- D											
<p>29.</p>	<p>(i) (D) IV (ii) (D) accelerate along $-\hat{i}$ (iii) (A) $V = V_0 + \alpha x$ (iv) (a) (C) $E_4 > E_3 > E_2 > E_1$ OR (b) (B) 2.6×10^6 m/s</p>	<p style="text-align: center;">1</p> <p style="text-align: center;">1</p> <p style="text-align: center;">1</p> <p style="text-align: center;">1</p>	<p style="text-align: center;">4</p>								
<p>30.</p>	<p>(i) (D) 6 (ii) (C) 3 (iii) (a) (C) 6 OR (b) $\sin^{-1}(0.225)$ (iv) (D) 10</p>	<p style="text-align: center;">1</p> <p style="text-align: center;">1</p> <p style="text-align: center;">1</p> <p style="text-align: center;">1</p>	<p style="text-align: center;">4</p>								
SECTION-E											
<p>31.</p>	<p>(a)</p> <table border="1" style="width: 100%; border-collapse: collapse;"> <tbody> <tr> <td style="padding: 5px;">(i) Obtaining expression for the capacitance</td> <td style="text-align: right; padding: 5px;">3</td> </tr> <tr> <td style="padding: 5px;">(ii) Finding the electric potential</td> <td style="text-align: right; padding: 5px;">2</td> </tr> <tr> <td style="padding: 5px;"> (i) at the surface</td> <td></td> </tr> <tr> <td style="padding: 5px;"> (ii) at the centre</td> <td></td> </tr> </tbody> </table> <p>(i) When a dielectric slab is inserted between the plates of capacitor, there is induced charge density σ_p which opposes the original charge density</p>	(i) Obtaining expression for the capacitance	3	(ii) Finding the electric potential	2	(i) at the surface		(ii) at the centre			
(i) Obtaining expression for the capacitance	3										
(ii) Finding the electric potential	2										
(i) at the surface											
(ii) at the centre											

(σ) on the plate of capacitance.
Electric field with dielectric medium is

$$E = \frac{(\sigma - \sigma_p)}{\epsilon_0}$$

$$V = E \times d = \frac{(\sigma - \sigma_p)}{\epsilon_0} d$$

$$(\sigma - \sigma_p) = \frac{\sigma}{K}$$

$$V = \frac{\sigma d}{\epsilon_0 K} = \frac{Qd}{A\epsilon_0 K}$$

$$C = \frac{Q}{V} = \frac{K\epsilon_0 A}{d}$$

(ii) Electric potential due to a point charge

$$V = \frac{1}{4\pi\epsilon_0} \frac{q}{r}$$

(i) At the surface

$$V = \frac{1}{4\pi\epsilon_0} \frac{q}{r} = \frac{9 \times 10^9 \times 6 \times 10^{-6}}{0.2}$$

$$V = 2.7 \times 10^5 \text{ V}$$

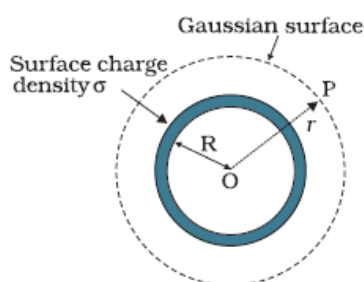
(ii) Since electric field inside the hollow sphere is zero, hence V is same as that of the surface and remains constant throughout the volume.

$$V = 2.7 \times 10^5 \text{ V}$$

OR

- | | | |
|-----|--|---|
| (b) | (i) Expression for electric field at a point lying | |
| | (i) inside | 1 |
| | (ii) outside | 2 |
| | (ii) Explanation | 2 |

(i) **Field inside the shell**



The Flux through the Gaussian surface is

$$= E \times 4\pi R^2$$

In this case Gaussian surface encloses no charge.

$$\text{Hence } E \times 4\pi R^2 = 0$$

$$E = 0$$

(Note: Award full credit of this part if a student writes directly $E=0$, mentioning as there is no charge enclosed by Gaussian surface)

1/2

1/2

1/2

1/2

1/2

1/2

1/2

1/2

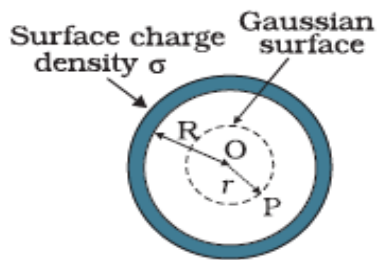
1/2

1/2

1/2

1/2

(ii) Field outside the shell-



Electric flux through Gaussian surface

$$E \times 4\pi r^2 = \frac{(\sigma 4\pi R^2)}{\epsilon_0}$$

Charge enclosed by the Gaussian surface

$$E \times 4\pi r^2 = \frac{(\sigma 4\pi R^2)}{\epsilon_0}$$

Using Gauss's law:

$$\int \vec{E} \cdot d\vec{s} = \frac{Q}{\epsilon_0}$$

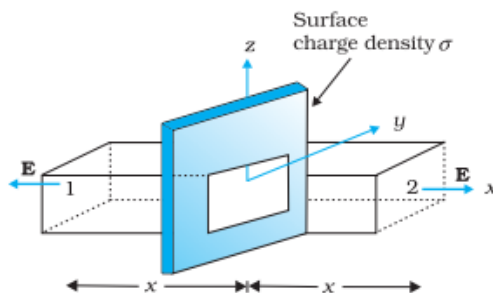
$$E \times 4\pi r^2 = \frac{(\sigma 4\pi R^2)}{\epsilon_0}$$

$$E = \frac{\sigma R^2}{\epsilon_0 r^2} = \frac{q}{4\pi\epsilon_0 r^2}$$

(ii) For conducting sheet,

Electric field due to a conducting sheet

$$E_c = \frac{\sigma}{\epsilon_0}$$



For non-conducting sheet

$$E_{nc} = \frac{\sigma}{2\epsilon_0}$$

Since surface charge density is same.

$$2E_{nc} = E_c$$

1/2

1/2

1/2

1/2

1/2

1/2

1/2

1/2

5

32.

- | | | |
|-----|---|-----|
| (a) | (i)(1) Meaning of current sensitivity, mentioning factors | 2 |
| | (2) Finding the required resistance | 1/2 |
| | (ii) Finding the induced current | 1/2 |

(i) (1). Current sensitivity of galvanometer is defined as the deflection per unit current.

Alternatively,

$$\frac{\phi}{I} = \frac{NBA}{K}$$

Factors

Number of turns in coil, Magnetic field intensity, Area of coil, Torsional Constant
(Any two)

1

1/2+1/2

$$(2) R = \frac{V}{I} - G \quad \text{for } (0-V) \text{ Range}$$

$$R_1 = \frac{V}{2I} - G \quad \text{for } (0-\frac{V}{2}) \text{ Range}$$

$$\frac{V}{I} = R + G$$

$$R_1 = \left(\frac{R+G}{2}\right) - G$$

$$R_1 = \frac{R-G}{2}$$

$$(ii) \phi = (2.0t^3 + 5.0t^2 + 6.0t) \text{ mWb}$$

$$|\varepsilon| = \frac{d\phi}{dt} = 50 \times 10^{-3} \text{ V}$$

$$I = \frac{|\varepsilon|}{R}$$

$$I = \frac{50 \times 10^{-3}}{5} \text{ A} = 10 \text{ mA}$$

1/2

1/2

1/2

1/2

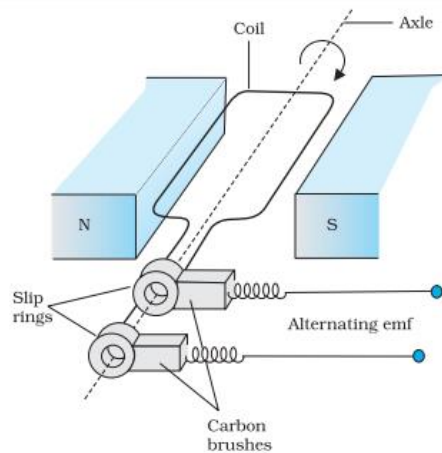
1/2

1/2

OR

(b)

- | | |
|---|---|
| (i) Obtaining the expression of emf induced | 3 |
| (ii) Calculation of mutual inductance | 2 |



1

(i) The flux at any instant t is

$$\phi = NBA \cos\theta = NBA \cos\omega t$$

1/2

From Faraday's law

$$\varepsilon = -\frac{d\phi_B}{dt}$$

1/2

$$= -NBA \frac{d}{dt} (\cos\omega t)$$

1/2

$$\varepsilon = -NBA \omega \sin\omega t$$

1/2

$$(ii) M = \frac{\mu_0 \pi r_1^2}{2r_2} = \frac{4\pi \times 10^{-7} \times \pi r_1^2}{2r_2}$$

1/2+1/2

$$= \frac{2 \times 10 \times 10^{-7} \times (10^{-2})^2}{100 \times 10^{-7}}$$

1/2

$$= 2 \times 10^{-10} \text{ H}$$

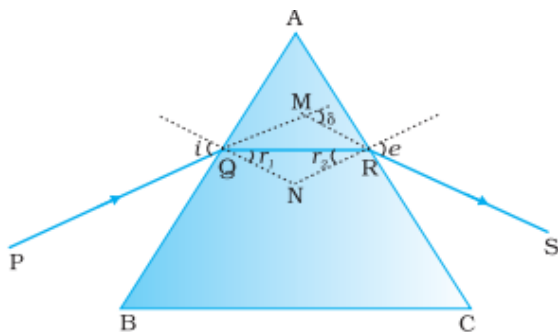
1/2

5

33.

(a)	(i) Tracing the path of ray	1/2
	Obtaining an expression for angle of deviation	1 1/2
	Drawing Graph	1
	(ii) Finding the refractive index	2

(i)



1/2

For quadrilateral AQNR,

$$\angle A + \angle QNR = 180^\circ \quad \text{--- (i)}$$

For triangle QNR

$$r_1 + r_2 + \angle QNR = 180^\circ \quad \text{---- (ii)}$$

comparing equation (i) and (ii)

$$r_1 + r_2 = A \quad \text{----- (iii)}$$

The angle of deviation

$$\delta = (i - r_1) + (e - r_2) \quad \text{----- (iv)}$$

from equation (iii) and (iv)

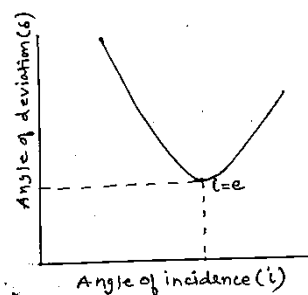
$$\delta = i + e - A$$

1/2

1/2

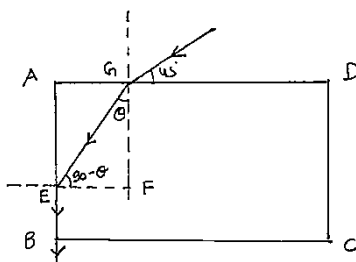
1/2

Graph



1

(ii)



$$\frac{\sin 45^\circ}{\sin \theta} = \mu$$

$$\frac{1}{\sqrt{2}} = \mu \sin \theta$$

For second surface,

$$\frac{\sin(90^\circ - \theta)}{\sin 90^\circ} = \frac{1}{\mu}$$

1/2

1/2

$$\frac{1}{\sqrt{2}} \frac{\cos \theta}{\sin \theta} = 1$$

$$\tan \theta = \frac{1}{\sqrt{2}}$$

From the triangle GEF

$$\sin \theta = \frac{1}{\sqrt{3}}$$

$$\mu = \sqrt{\frac{3}{2}}$$

OR

(b)	(i) Expression for resultant intensity	3
	(ii) Ratio of intensities	2

(i) $y_1 = a \cos \omega t$

$$y_2 = a \cos(\omega t + \phi)$$

According to the principle of superposition

$$y = y_1 + y_2$$

$$y = a \cos \omega t + a \cos(\omega t + \phi)$$

$$y = a \cos \omega t + a \cos \omega t \cos \phi - a \sin \omega t \sin \phi$$

$$y = a \cos \omega t (1 + \cos \phi) - a \sin \phi \sin \omega t$$

Let,

$$a(1 + \cos \phi) = A \cos \theta \quad \text{----- (i)}$$

$$a \sin \phi = A \sin \theta \quad \text{-----(ii)}$$

Squaring and adding equation (i) and (ii)

$$A^2 = a^2(1 + \cos \phi)^2 + a^2 \sin^2 \phi$$

$$= a^2(1 + \cos^2 \phi + 2 \cos \phi) + a^2 \sin^2 \phi$$

$$= 2a^2(1 + \cos \phi)$$

$$= 4a^2 \cos^2 \phi / 2$$

$$I \propto A^2$$

$$I = kA^2$$

where k is constant

$$I = 4ka^2 \cos^2 \phi / 2$$

[Award full credit for this part for any other alternative methods]

(ii) $\phi_1 = \frac{2\pi}{\lambda} \times \frac{\lambda}{6} = \pi/3$

$$I_1 = 4I_0 \cos^2 \phi / 2$$

$$= 4I_0 \cos^2(\pi/6)$$

$$I_1 = 3I_0$$

$$\phi_2 = \frac{2\pi}{\lambda} \times \frac{\lambda}{12} = \pi/6$$

$$I_2 = 4I_0 \cos^2(\pi/12)$$

$$I_2 = 4I_0 \cos^2 15^\circ$$

$$\frac{I_1}{I_2} = \frac{3}{4 \cos^2 15^\circ}$$

1/2

1/2

1/2

1/2

1/2

1/2

1/2

1/2

1/2

1/2

1/2

1/2

5

